NSN 5962-01-473-2145

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Communications and data systems
Features Provided:
Monolithic and electrostatic sensitive and erasable and programmable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Product Name:
Microelectronic device, eeprom
Voltage Rating And Type Per Characteristic:
-0.3 volts input and 6.25 volts input
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Eeprom
Special Features:
Altered item/program as 28c256/checksum (hex) 00167a90/write speed 10 ms/endurance 100, 000 cycles
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0